

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	96808	(gate) near (dielectric or insulat\$3)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
2	BRS	L2	34007	((gate) near (dielectric or insulat\$3)) near35 (source or drain)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
3	BRS	L3	2460	((gate) near (dielectric or insulat\$3)) near35 (sidewall or side near wall) near15 (source or drain))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
4	BRS	L4	3	((gate) near (dielectric or insulat\$3)) near35 (sidewall or side near wall) near15 (source or drain)) near25 (irradiat\$3 or radiat\$3)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs
5	BRS	L5	29	(((((dielectric or insulat\$3)) near35 (sidewall or side near wall) near15 (source or drain))) near25 (irradiat\$3 or radiat\$3)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
6	BRS	L6	12	5 and (electrode)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
7	BRS	L7	83431	(upper near3 electrode)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
8	BRS	L8	37605	(upper near3 electrode) near25 (lower near3 electrode)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs
9	BRS	L9	5828	(capacitor) near5 ((upper near3 electrode) near25 (lower near3 electrode))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
10	BRS	L10	4205	((capacitor) near5 ((upper near3 electrode) near25 (lower near3 electrode))) near25 (dielectric or insulat\$3)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
11	BRS	L11	2496	((capacitor) near ((upper near3 electrode) near25 (lower near3 electrode))) near25 (dielectric or insulat\$3))	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
12	BRS	L12	7	((capacitor) near ((upper near3 electrode) near25 (lower near3 electrode))) near25 (dielectric or insulat\$3)) near35 (irradiat\$3 or radiat\$3)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B